TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC5064

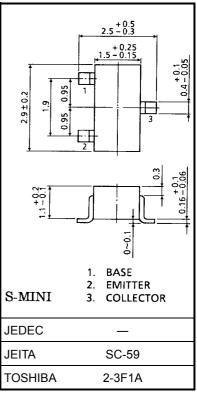
VHF~UHF Band Low Noise Amplifier Applications

Unit: mm

- Low noise figure, high gain.
- NF = 1.1dB, $|S_{21e}|^2 = 12dB$ (f = 1 GHz)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V_{CBO}	20	V	
Collector-emitter voltage	V _{CEO}	12	V	
Emitter-base voltage	V _{EBO}	3	V	
Base current	Ι _Β	15	mA	
Collector current	I _C	30	mA	
Collector power dissipation	PC	150	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	T _{stg}	-55~125	°C	



Weight: 0.012 g (typ.)

Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Transition frequency	f _T	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$	5	7	_	GHz
Insertion gain	S _{21e} ² (1)	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}, f = 500 \text{ MHz}$	_	17	_	dB
mseriion gain	S _{21e} ² (2)	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}, f = 1 \text{ GHz}$	12	_	ub l	
Noise figure	NF (1)	$V_{CE} = 5 \text{ V}, I_{C} = 3 \text{ mA}, f = 500 \text{ MHz}$		1		dB
	NF (2)	$V_{CE} = 5 \text{ V}, I_{C} = 3 \text{ mA}, f = 1 \text{ GHz}$		1.1	2.0	ub

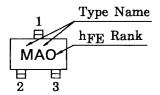
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 10 \text{ V}, I_{E} = 0$	_	_	1	μА
Emitter cut-off current	I _{EBO}	V _{EB} = 1 V, I _C = 0	_	_	1	μА
DC current gain	h _{FE} (Note 1)	V _{CE} = 5 V, I _C = 10 mA	80	_	240	
Output capacitance	C _{ob}	V _{CB} = 5 V, I _F = 0, f = 1 MHz (Note 2)	_	0.7	_	pF
Reverse transfer capacitance	C _{re}	$A \cap CB = A \cap A$	_	0.45	0.9	pF

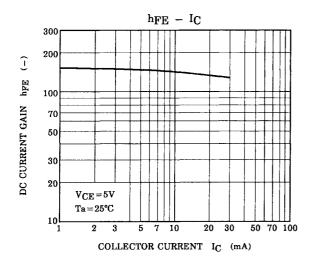
Note 1: hFE classification O: 80~160, Y: 120~240

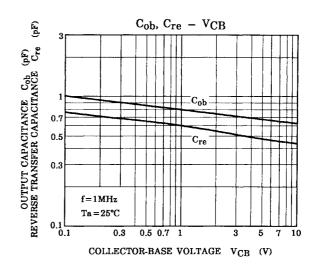
Note 2: C_{re} is measured by 3 terminal method with capacitance bridge.

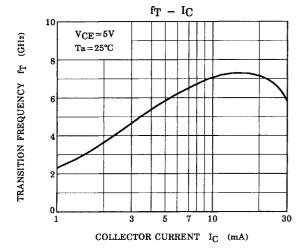
Marking

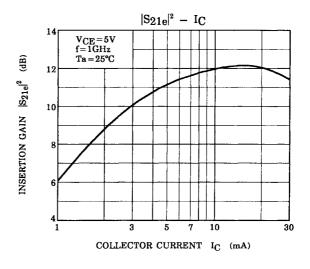


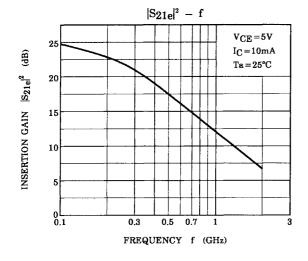
2 2003-03-19

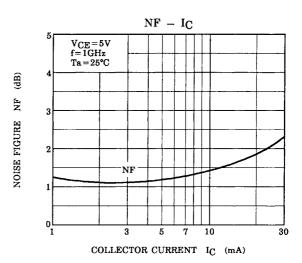




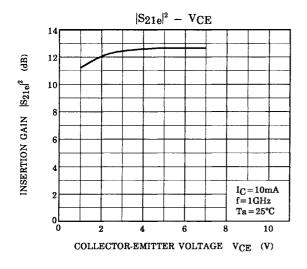


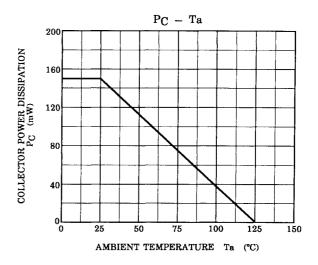






3





S-Parameter $Z_0 = 50 \Omega$, Ta = 25°C

$V_{CE} = 5 V$, $I_C = 5 mA$

Frequency	S11		S21		S1	12	S22		
(MHz)	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	
200	0.753	-43.7	10.247	140.6	0.040	65.6	0.827	-22.6	
400	0.531	-75.1	7.684	117.1	0.060	57.1	0.648	-30.3	
600	0.384	-96.4	5.815	103.0	0.074	56.1	0.551	-32.0	
800	0.305	-112.6	4.523	93.6	0.086	57.0	0.500	-32.3	
1000	0.255	-126.5	3.788	86.3	0.099	58.9	0.472	-32.4	
1200	0.224	-138.4	3.244	80.7	0.112	60.2	0.455	-32.2	
1400	0.203	-150.1	2.833	75.4	0.127	60.3	0.442	-32.6	
1600	0.187	-159.4	2.529	70.6	0.139	60.0	0.434	-33.0	
1800	0.174	-166.5	2.283	66.7	0.150	60.3	0.429	-32.6	
2000	0.176	-171.2	2.107	63.0	0.164	59.2	0.428	-32.2	

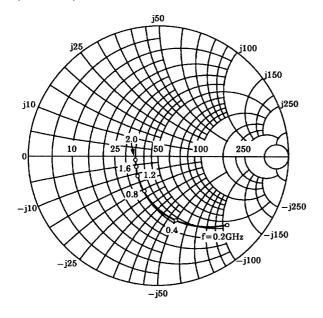
$V_{CE} = 5 \text{ V}, I_C = 10 \text{ mA}$

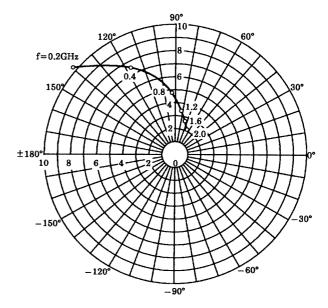
Frequency	S11		S21		S12		S22	
(MHz)	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.591	-58.0	14.955	129.6	0.034	64.3	0.714	-27.5
400	0.367	-90.3	9.581	107.5	0.052	61.9	0.534	-30.8
600	0.260	-110.7	6.781	96.1	0.067	63.9	0.462	-30.1
800	0.209	-126.9	5.207	88.6	0.083	65.2	0.428	-29.2
1000	0.178	-141.8	4.269	82.5	0.100	66.4	0.412	-28.6
1200	0.160	-153.7	3.618	77.7	0.117	66.7	0.403	-28.3
1400	0.150	-166.3	3.152	72.7	0.135	65.4	0.398	-28.8
1600	0.141	-175.2	2.801	68.7	0.149	64.0	0.393	-29.4
1800	0.130	178.2	2.521	65.0	0.163	63.4	0.392	-29.0
2000	0.133	174.0	2.314	61.7	0.179	61.3	0.395	-28.6

4 2003-03-19

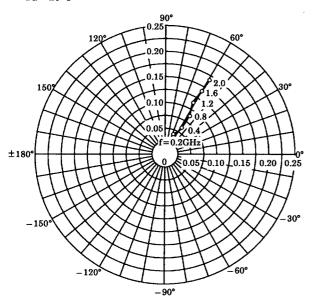
 $\begin{array}{l} S_{11e} \\ V_{CE} = 5V \\ I_{C} = 5mA \\ Ta = 25^{\circ}C \\ (UNIT:\Omega) \end{array}$



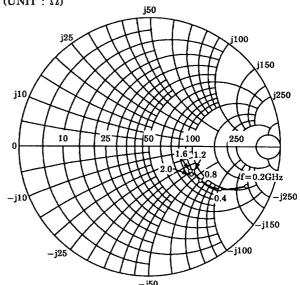




 S_{12e} $V_{CE} = 5V$ $I_{C} = 5mA$ $T_{a} = 25^{\circ}C$

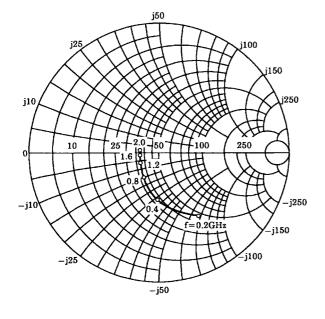


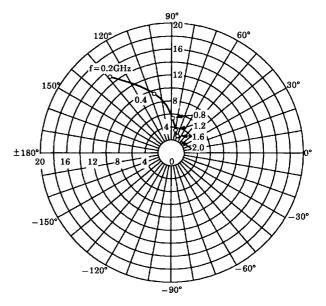
S22e VCE=5V IC=5mA Ta=25°C (UNIT: Ω)



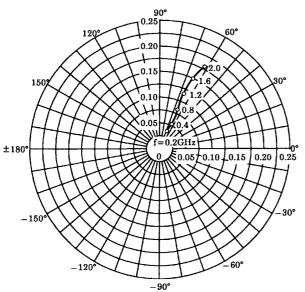
 $\begin{array}{l} S_{11e} \\ V_{CE} = 5V \\ I_{C} = 10 mA \\ Ta = 25^{\circ}C \\ (UNIT:\Omega) \end{array}$







 $\begin{array}{l} S_{12e} \\ V_{CE} = 5V \\ I_{C} = 10 \text{mA} \\ Ta = 25^{\circ}C \end{array}$



S22e $V_{CE} = 5V$ $I_{C} = 10 mA$ $T_{a} = 25^{\circ}C$ (UNIT : Ω) $_{j50}$ $_{j100}$ $_{j150}$ $_{j150}$

-j50

6

RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other
 rights of the third parties which may result from its use. No license is granted by implication or otherwise under
 any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.